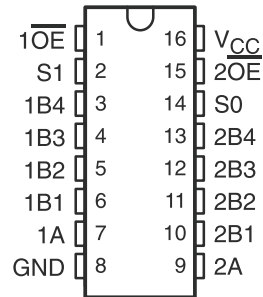


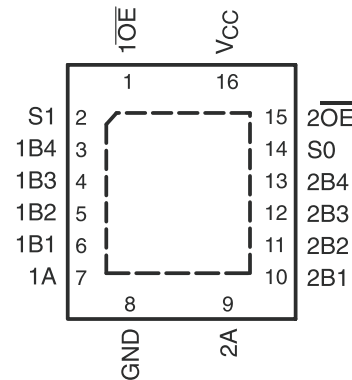
## FEATURES

- SN74CBT3253C Functionally Identical to Industry-Standard '3253 Function
- Undershoot Protection for Off-Isolation on A and B Ports up to -2 V
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance ( $r_{on}$ ) Characteristics ( $r_{on} = 3\ \Omega$  Typical)
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion ( $C_{io(OFF)} = 5.5\ \text{pF}$  Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption ( $I_{CC} = 3\ \mu\text{A}$  Max)
- $V_{CC}$  Operating Range From 4 V to 5.5 V
- Data I/Os Support 0 to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports I<sup>2</sup>C Bus Expansion
- Supports Both Digital and Analog Applications: USB Interface, Bus Isolation, Low-Distortion Signal Gating

D, DB, DBQ, OR PW PACKAGE  
(TOP VIEW)



RGY PACKAGE  
(TOP VIEW)



## DESCRIPTION/ORDERING INFORMATION

The SN74CBT3253C is a high-speed TTL-compatible FET multiplexer/demultiplexer with low ON-state resistance ( $r_{on}$ ), allowing for minimal propagation delay. Active Undershoot-Protection Circuitry on the A and B ports of the SN74CBT3253C provides protection for undershoot up to -2 V by sensing an undershoot event and ensuring that the switch remains in the proper OFF state.

The SN74CBT3253C is organized as two 1-of-4 multiplexer/demultiplexers with separate output-enable ( $1\overline{OE}$ ,  $2\overline{OE}$ ) inputs. The select (S0, S1) inputs control the data path of each multiplexer/demultiplexer. When  $\overline{OE}$  is low, the associated multiplexer/demultiplexer is enabled, and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the associated multiplexer/demultiplexer is disabled, and a high-impedance state exists between the A and B ports.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN74CBT3253C

## DUAL 1-OF-4 FET MULTIPLEXER/DEMULTIPLEXER

### 5-V BUS SWITCH WITH –2-V UNDERSHOOT PROTECTION

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## DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

## ORDERING INFORMATION

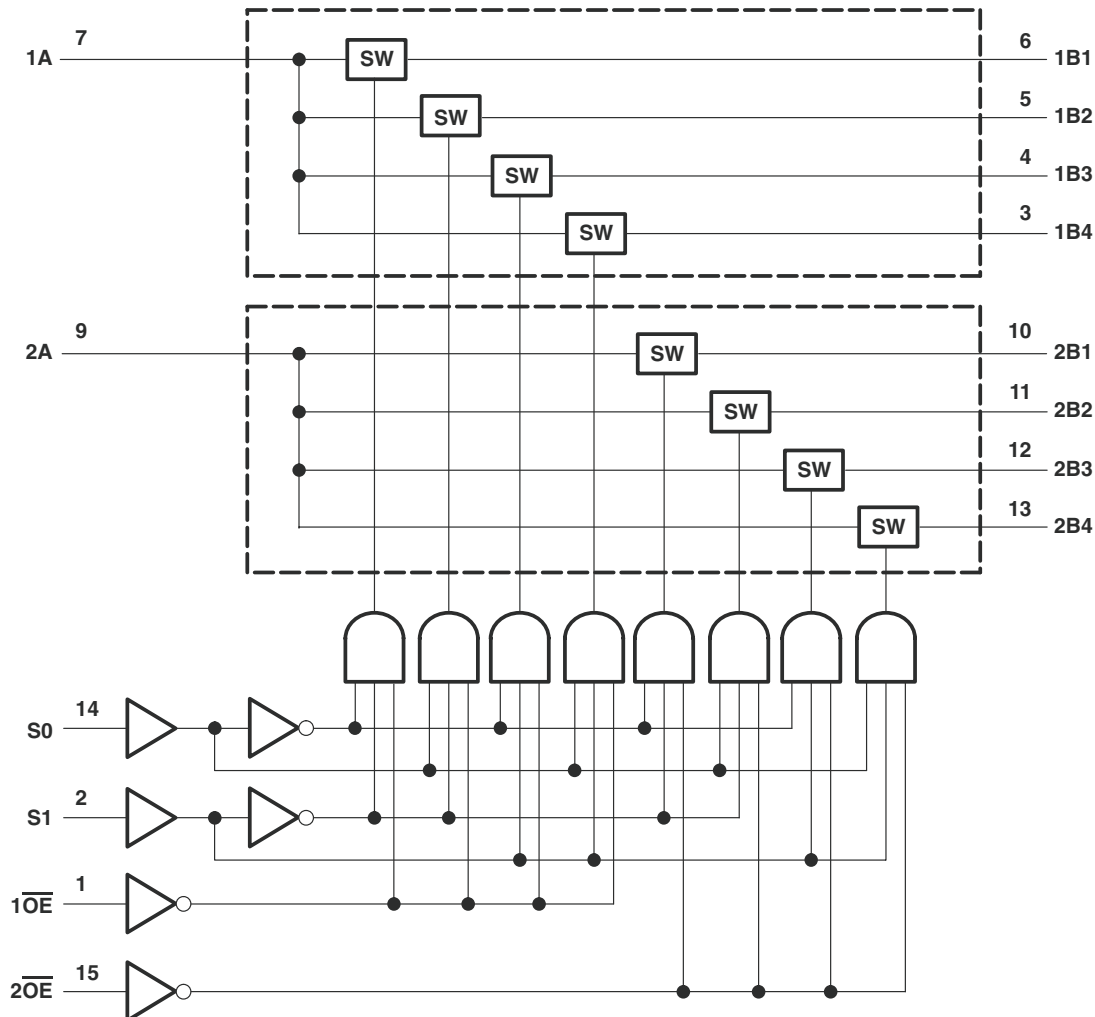
| $T_A$         | PACKAGE <sup>(1)</sup> |              | ORDERABLE PART NUMBER | TOP-SIDE MARKING |
|---------------|------------------------|--------------|-----------------------|------------------|
| –40°C to 85°C | QFN – RGY              | Reel of 1000 | SN74CBT3253CRGYR      | CU253C           |
|               | SOIC – D               | Tube of 40   | SN74CBT3253CD         | CBT3253C         |
|               |                        | Reel of 2500 | SN74CBT3253CDR        |                  |
|               | SSOP – DB              | Tube of 80   | SN74CBT3253CDB        | CU253C           |
|               |                        | Reel of 2000 | SN74CBT3253CDBR       |                  |
|               | SSOP (QSOP) – DBQ      | Reel of 2500 | SN74CBT3253CDBQR      | CU253C           |
|               | TSSOP – PW             | Tube of 90   | SN74CBT3253CPW        | CU253C           |
|               |                        | Reel of 2000 | SN74CBT3253CPWR       |                  |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

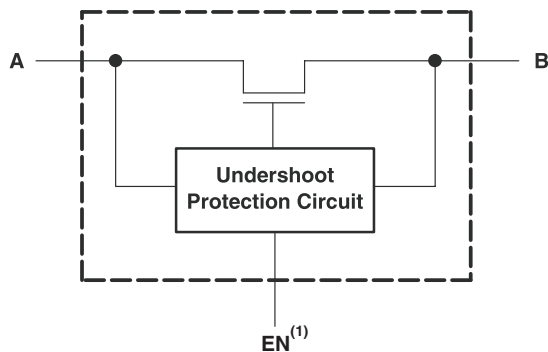
## FUNCTION TABLE (each multiplexer/demultiplexer)

| INPUTS          |    |    | INPUT/OUTPUT<br>A | FUNCTION         |
|-----------------|----|----|-------------------|------------------|
| $\overline{OE}$ | S1 | S0 |                   |                  |
| L               | L  | L  | B1                | A port = B1 port |
| L               | L  | H  | B2                | A port = B2 port |
| L               | H  | L  | B3                | A port = B3 port |
| L               | H  | H  | B4                | A port = B4 port |
| H               | X  | X  | X                 | Disconnect       |

### LOGIC DIAGRAM (POSITIVE LOGIC)



### SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) EN is the internal enable signal applied to the switch.

# SN74CBT3253C

## DUAL 1-OF-4 FET MULTIPLEXER/DEMULTIPLEXER

### 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

SCDS123B–JULY 2003–REVISED JANUARY 2007

#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|               |  |                            | MIN  | MAX  | UNIT |
|---------------|--|----------------------------|------|------|------|
| $V_{CC}$      | Supply voltage                                       |                            | -0.5 | 7    | V    |
| $V_{IN}$      | Control input voltage range <sup>(2) (3)</sup>       |                            | -0.5 | 7    | V    |
| $V_{I/O}$     | Switch I/O voltage range <sup>(2) (3) (4)</sup>      |                            | -0.5 | 7    | V    |
| $I_{IK}$      | Control input clamp current                          | $V_{IN} < 0$               |      | -50  | mA   |
| $I_{I/OK}$    | I/O port clamp current                               | $V_{I/O} < 0$              |      | -50  | mA   |
| $I_{I/O}$     | ON-state switch current <sup>(5)</sup>               |                            |      | ±128 | mA   |
|               | Continuous current through $V_{CC}$ or GND terminals |                            |      | ±100 | mA   |
| $\theta_{JA}$ | Package thermal impedance                            | D package <sup>(6)</sup>   |      | 73   | °C/W |
|               |  | DB package <sup>(6)</sup>  |      | 82   |      |
|               |  | DBQ package <sup>(6)</sup> |      | 90   |      |
|               |  | PW package <sup>(6)</sup>  |      | 108  |      |
|               |  | RGY package <sup>(7)</sup> |      | 39   |      |
| $T_{stg}$     | Storage temperature range                            |                            | -65  | 150  | °C   |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to ground unless otherwise specified.
- (3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (4)  $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ .
- (5)  $I_I$  and  $I_O$  are used to denote specific conditions for  $I_{I/O}$ .
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.
- (7) The package thermal impedance is calculated in accordance with JESD 51-5.

#### Recommended Operating Conditions<sup>(1)</sup>

|           |                                  |  | MIN | MAX | UNIT |
|-----------|----------------------------------|--|-----|-----|------|
| $V_{CC}$  | Supply voltage                   |  | 4   | 5.5 | V    |
| $V_{IH}$  | High-level control input voltage |  | 2   | 5.5 | V    |
| $V_{IL}$  | Low-level control input voltage  |  | 0   | 0.8 | V    |
| $V_{I/O}$ | Data input/output voltage        |  | 0   | 5.5 | V    |
| $T_A$     | Operating free-air temperature   |  | -40 | 85  | °C   |

- (1) All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## Electrical Characteristics<sup>(1)</sup>

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER                      |                | TEST CONDITIONS   |  | MIN | TYP <sup>(2)</sup> | MAX      | UNIT          |
|--------------------------------|----------------|---|--|-----|--------------------|----------|---------------|
| $V_{IK}$                       | Control inputs | $V_{CC} = 4.5\text{ V}$ ,                               | $I_{IN} = -18\text{ mA}$   |     |                    | -1.8     | V             |
| $V_{IKU}$                      | Data inputs    | $V_{CC} = 5\text{ V}$ ,                                 | $0\text{ mA} > I_I \geq -50\text{ mA}$ ,<br>$V_{IN} = V_{CC}$ or GND, Switch OFF     |     |                    | -2       | V             |
| $I_{IN}$                       | Control inputs | $V_{CC} = 5.5\text{ V}$ ,                               | $V_{IN} = V_{CC}$ or GND   |     |                    | $\pm 1$  | $\mu\text{A}$ |
| $I_{OZ}$ <sup>(3)</sup>        |                | $V_{CC} = 5.5\text{ V}$ ,                               | $V_O = 0$ to $5.5\text{ V}$ ,<br>$V_I = 0$ , Switch OFF,<br>$V_{IN} = V_{CC}$ or GND |     |                    | $\pm 10$ | $\mu\text{A}$ |
| $I_{off}$                      |                | $V_{CC} = 0$ ,  | $V_O = 0$ to $5.5\text{ V}$ ,<br>$V_I = 0$   |     |                    | 10       | $\mu\text{A}$ |
| $I_{CC}$                       |                | $V_{CC} = 5.5\text{ V}$ ,                               | $I_{I/O} = 0$ ,<br>$V_{IN} = V_{CC}$ or GND, Switch ON or OFF                        |     |                    | 3        | $\mu\text{A}$ |
| $\Delta I_{CC}$ <sup>(4)</sup> | Control inputs | $V_{CC} = 5.5\text{ V}$ ,                               | One input at $3.4\text{ V}$ , Other inputs at $V_{CC}$ or GND                        |     |                    | 2.5      | $\text{mA}$   |
| $C_{in}$                       | Control inputs | $V_{IN} = 3\text{ V}$ or 0                              |  |     | 3.5                |          | $\text{pF}$   |
| $C_{io(OFF)}$                  | A port         | $V_{I/O} = 3\text{ V}$ or 0,                            | Switch OFF, $V_{IN} = V_{CC}$ or GND   |     | 14                 |          | $\text{pF}$   |
|                                | B port         |   |  |     | 5.5                |          |               |
| $C_{io(ON)}$                   |                | $V_{I/O} = 3\text{ V}$ or 0,                            | Switch ON, $V_{IN} = V_{CC}$ or GND  |     | 22                 |          | $\text{pF}$   |
| $r_{on}$ <sup>(5)</sup>        |                | $V_{CC} = 4\text{ V}$ ,<br>TYP at $V_{CC} = 4\text{ V}$ | $V_I = 2.4\text{ V}$ , $I_O = -15\text{ mA}$   |     | 8                  | 12       | $\Omega$      |
|                                |                | $V_{CC} = 4.5\text{ V}$                                 | $V_I = 0$ , $I_O = 64\text{ mA}$   |     | 3                  | 6        |               |
|                                |                |   | $I_O = 30\text{ mA}$   |     | 3                  | 6        |               |
|                                |                |   | $V_I = 2.4\text{ V}$ , $I_O = -15\text{ mA}$   |     | 5                  | 10       |               |

(1)  $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to data pins.

(2) All typical values are at  $V_{CC} = 5\text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

(3) For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.

(4) This is the increase in supply current for each input that is at the specified voltage level, rather than  $V_{CC}$  or GND

(5) Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

## Switching Characteristics

over recommended operating free-air temperature range,  $C_L = 50\text{ pF}$  (unless otherwise noted) (see [Figure 3](#))

| PARAMETER               | FROM<br>(INPUT) | TO<br>(OUTPUT) | $V_{CC} = 4\text{ V}$ |      | $V_{CC} = 5\text{ V}$<br>$\pm 0.5\text{ V}$ |      | UNIT |
|-------------------------|-----------------|----------------|-----------------------|------|---|------|------|
|                         |                 |                | MIN                   | MAX  | MIN   | MAX  |      |
| $t_{pd}$ <sup>(1)</sup> | A or B          | B or A         |                       | 0.24 |   | 0.15 | ns   |
| $t_{pd(s)}$             | S               | A              |                       | 5.9  | 1.5   | 5.4  | ns   |
| $t_{en}$                | S               | B              |                       | 6.2  | 1.5   | 5.8  | ns   |
|                         | $\overline{OE}$ | A or B         |                       | 5.7  | 1.5   | 5.3  |      |
| $t_{dis}$               | S               | B              |                       | 6.2  | 1.5   | 5.8  | ns   |
|                         | $\overline{OE}$ | A or B         |                       | 5.7  | 1.5   | 5.3  |      |

(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

# SN74CBT3253C

## DUAL 1-OF-4 FET MULTIPLEXER/DEMULTIPLEXER

### 5-V BUS SWITCH WITH -2-V UNDERSHOOT PROTECTION

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#### Undershoot Characteristics

See [Figure 1](#) and [Figure 2](#)

| PARAMETER  | TEST CONDITIONS            |             |                          | MIN | TYP <sup>(1)</sup> | MAX | UNIT |
|------------|----------------------------|-------------|--------------------------|-----|--------------------|-----|------|
| $V_{OUTU}$ | $V_{CC} = 5.5 \text{ V}$ , | Switch OFF, | $V_{IN} = V_{CC}$ or GND | 2   | $V_{OH} - 0.3$     |     | V    |

(1) All typical values are at  $V_{CC} = 5 \text{ V}$  (unless otherwise noted),  $T_A = 25^\circ\text{C}$ .

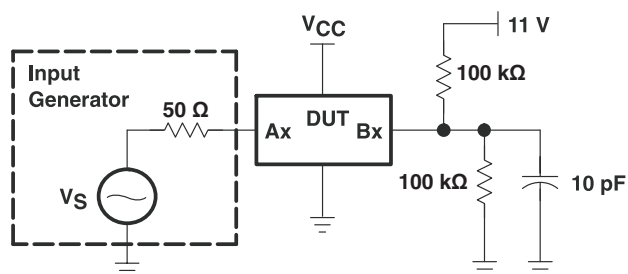


Figure 1. Device Test Setup

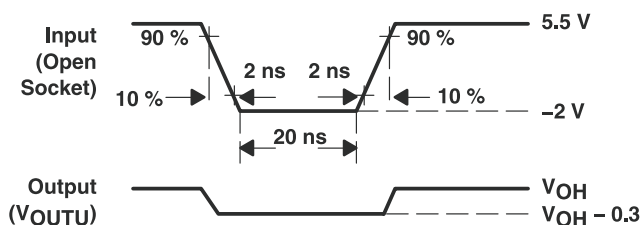
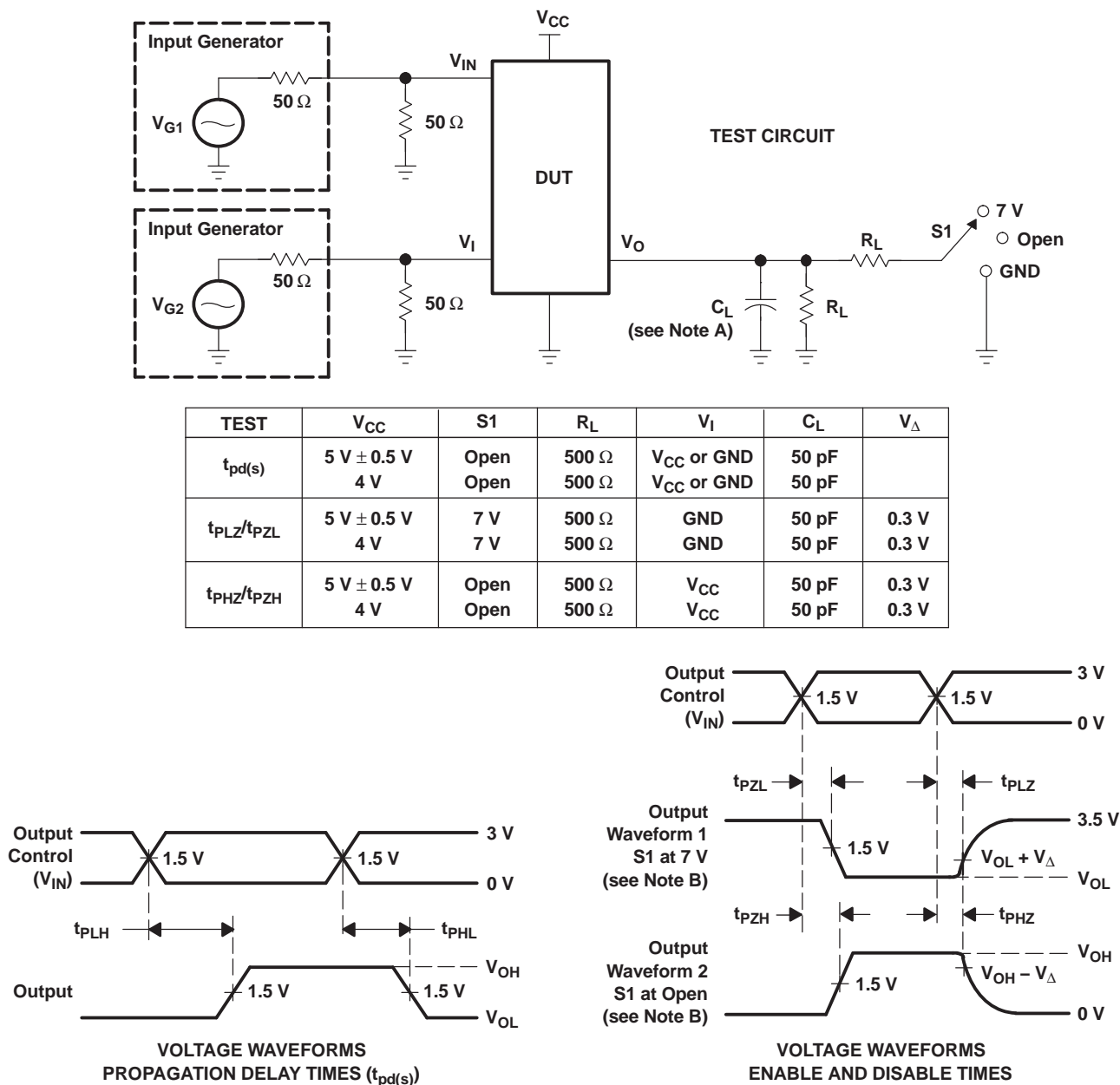


Figure 2. Transient Input Voltage ( $V_i$ ) and Output Voltage ( $V_{OUTU}$ ) Waveforms (Switch OFF)

## PARAMETER MEASUREMENT INFORMATION



- NOTES:
- C<sub>L</sub> includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> ≤ 2.5 ns, t<sub>f</sub> ≤ 2.5 ns.
  - The outputs are measured one at a time, with one transition per measurement.
  - t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd(s)</sub>. The t<sub>pd</sub> propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
  - All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms

## PACKAGING INFORMATION

| Orderable part number            | Status<br>(1) | Material type<br>(2) | Package   Pins  | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|----------------------------------|---------------|----------------------|-----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">SN74CBT3253CD</a>    | Active        | Production           | SOIC (D)   16   | 40   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| SN74CBT3253CD.B                  | Active        | Production           | SOIC (D)   16   | 40   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| <a href="#">SN74CBT3253CDBQR</a> | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | CU253C              |
| SN74CBT3253CDBQR.B               | Active        | Production           | SSOP (DBQ)   16 | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | CU253C              |
| <a href="#">SN74CBT3253CDBR</a>  | Active        | Production           | SSOP (DB)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| SN74CBT3253CDBR.B                | Active        | Production           | SSOP (DB)   16  | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| <a href="#">SN74CBT3253CDR</a>   | Active        | Production           | SOIC (D)   16   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| SN74CBT3253CDR.B                 | Active        | Production           | SOIC (D)   16   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| SN74CBT3253CDRE4                 | Active        | Production           | SOIC (D)   16   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| SN74CBT3253CDRG4                 | Active        | Production           | SOIC (D)   16   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CBT3253C            |
| <a href="#">SN74CBT3253CPW</a>   | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| SN74CBT3253CPW.B                 | Active        | Production           | TSSOP (PW)   16 | 90   TUBE             | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| <a href="#">SN74CBT3253CPWR</a>  | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| SN74CBT3253CPWR.B                | Active        | Production           | TSSOP (PW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CU253C              |
| <a href="#">SN74CBT3253CRGYR</a> | Active        | Production           | VQFN (RGY)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | CU253C              |
| SN74CBT3253CRGYR.B               | Active        | Production           | VQFN (RGY)   16 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 85    | CU253C              |

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.



**(6) Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN74CBT3253CDBQR | SSOP         | DBQ             | 16   | 2500 | 330.0              | 12.5               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| SN74CBT3253CDBR  | SSOP         | DB              | 16   | 2000 | 330.0              | 16.4               | 8.35    | 6.6     | 2.4     | 12.0    | 16.0   | Q1            |
| SN74CBT3253CDR   | SOIC         | D               | 16   | 2500 | 330.0              | 16.4               | 6.5     | 10.3    | 2.1     | 8.0     | 16.0   | Q1            |
| SN74CBT3253CPWR  | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| SN74CBT3253CRGYR | VQFN         | RGY             | 16   | 3000 | 330.0              | 12.4               | 3.8     | 4.3     | 1.5     | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74CBT3253CDBQR | SSOP         | DBQ             | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| SN74CBT3253CDBR  | SSOP         | DB              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| SN74CBT3253CDR   | SOIC         | D               | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| SN74CBT3253CPWR  | TSSOP        | PW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |
| SN74CBT3253CRGYR | VQFN         | RGY             | 16   | 3000 | 353.0       | 353.0      | 32.0        |

## TUBE

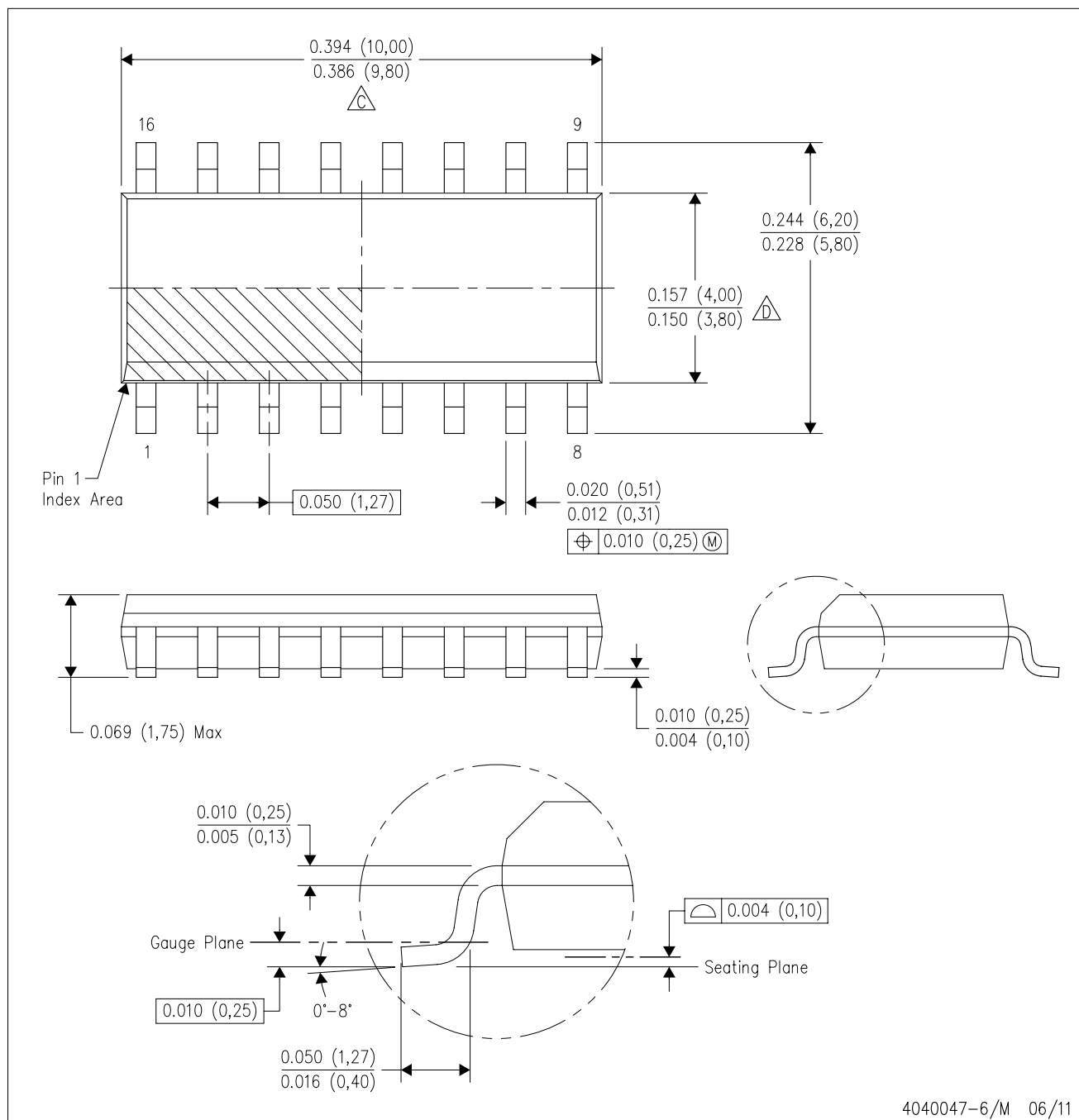




\*All dimensions are nominal

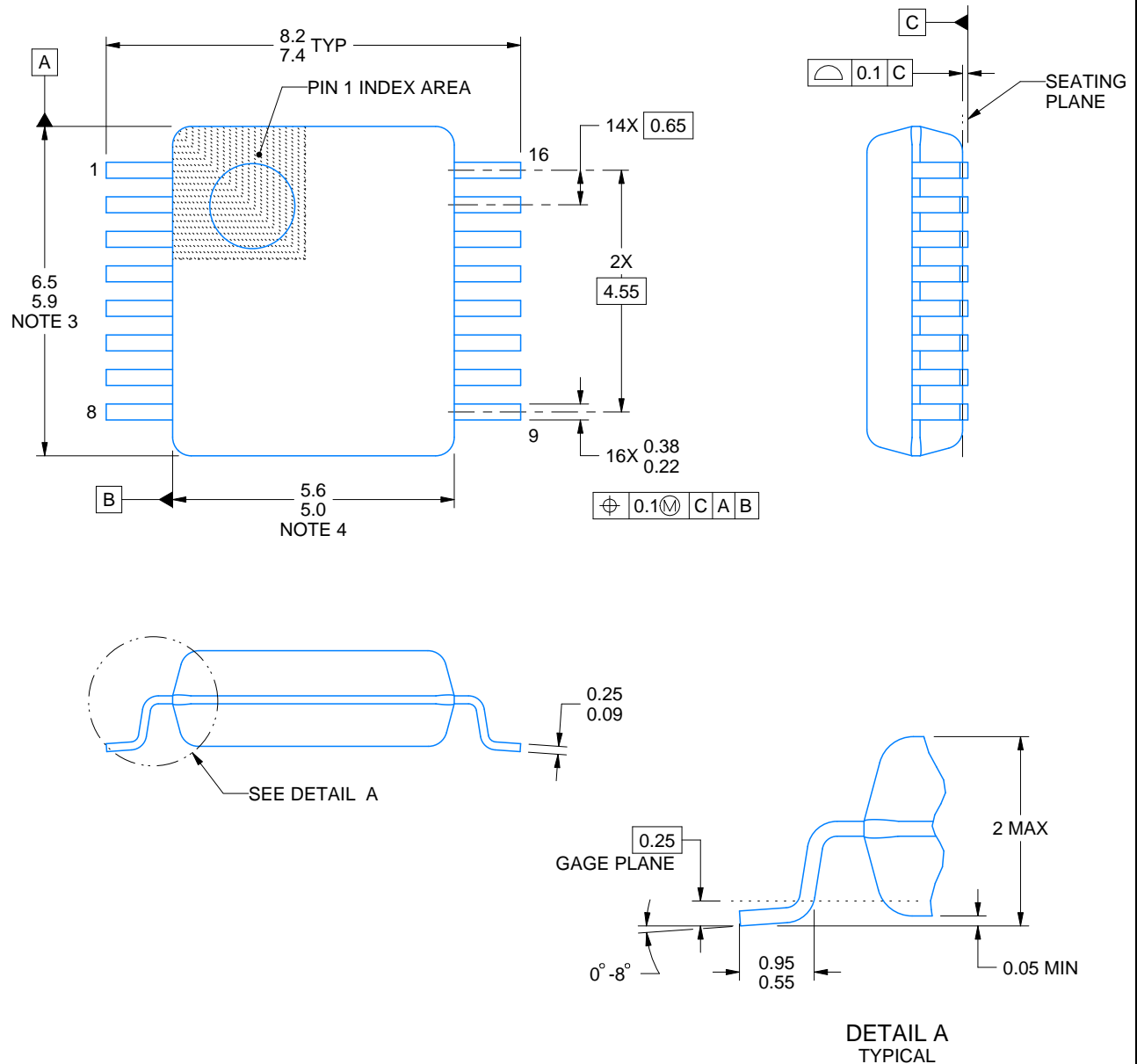
| Device           | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| SN74CBT3253CD    | D            | SOIC         | 16   | 40  | 507    | 8      | 3940   | 4.32   |
| SN74CBT3253CD.B  | D            | SOIC         | 16   | 40  | 507    | 8      | 3940   | 4.32   |
| SN74CBT3253CPW   | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |
| SN74CBT3253CPW.B | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |

## D (R-PDSO-G16)

# PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.



4220763/A 05/2022

## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-150.



# EXAMPLE STENCIL DESIGN

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220763/A 05/2022

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.





4220204/B 12/2023

## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



SOLDER MASK DETAILS

4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

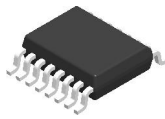


SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

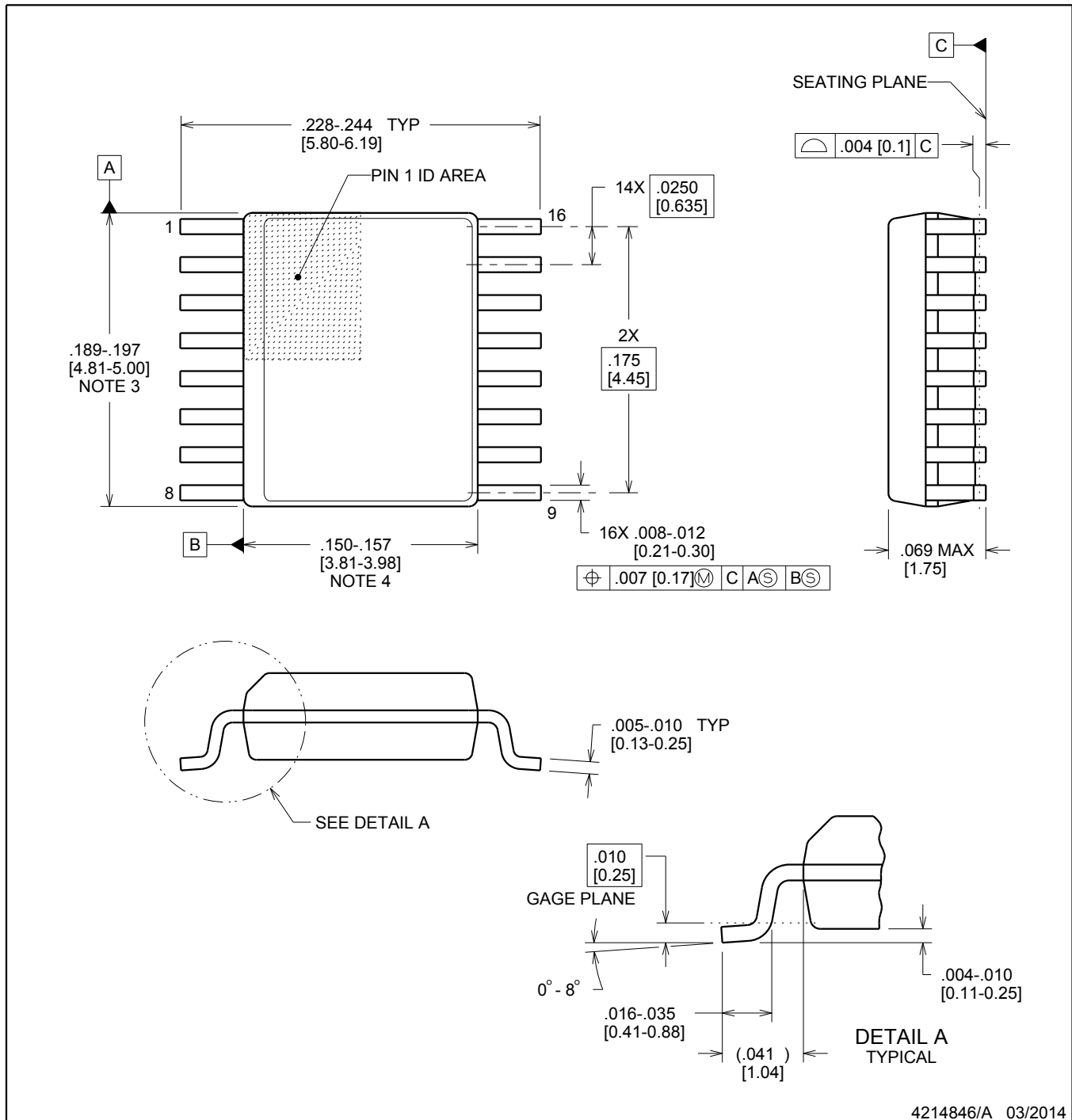


**DBQ0016A**

# PACKAGE OUTLINE

**SSOP - 1.75 mm max height**

SHRINK SMALL-OUTLINE PACKAGE



4214846/A 03/2014

## NOTES:

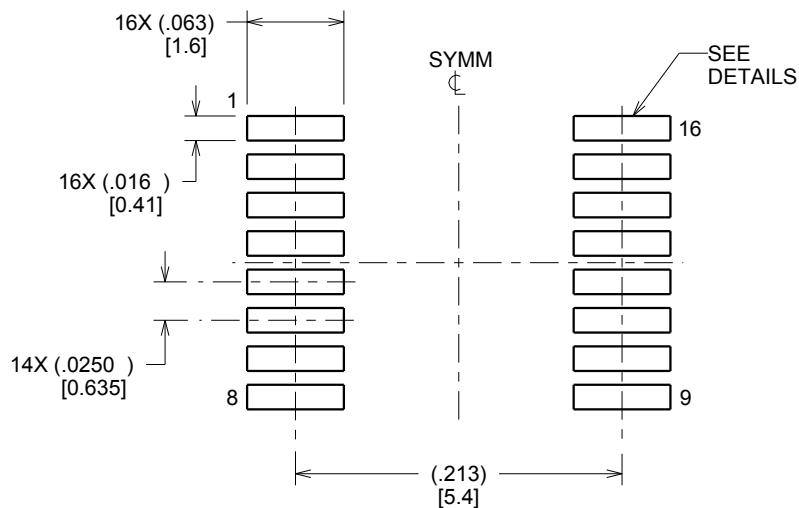
- Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- This dimension does not include interlead flash.
- Reference JEDEC registration MO-137, variation AB.

# EXAMPLE BOARD LAYOUT

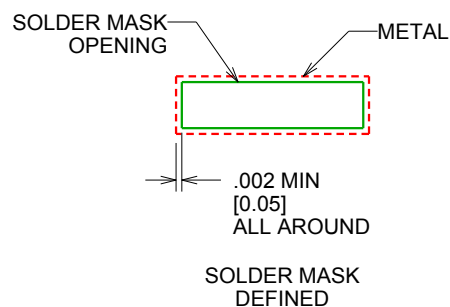
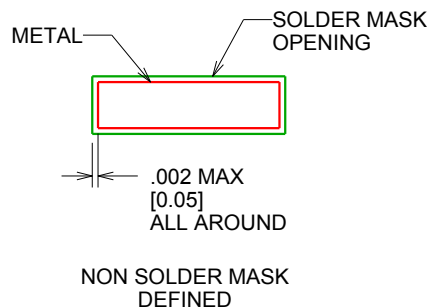
DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4214846/A 03/2014

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

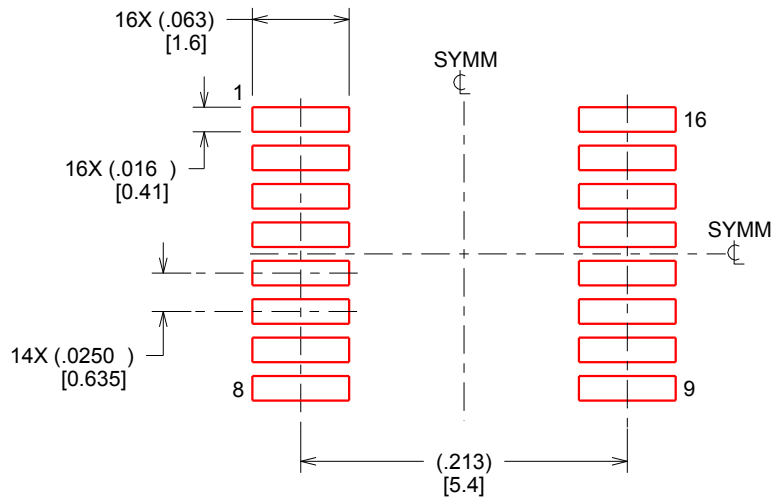
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBQ0016A

SSOP - 1.75 mm max height

SHRINK SMALL-OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.127 MM] THICK STENCIL  
SCALE:8X

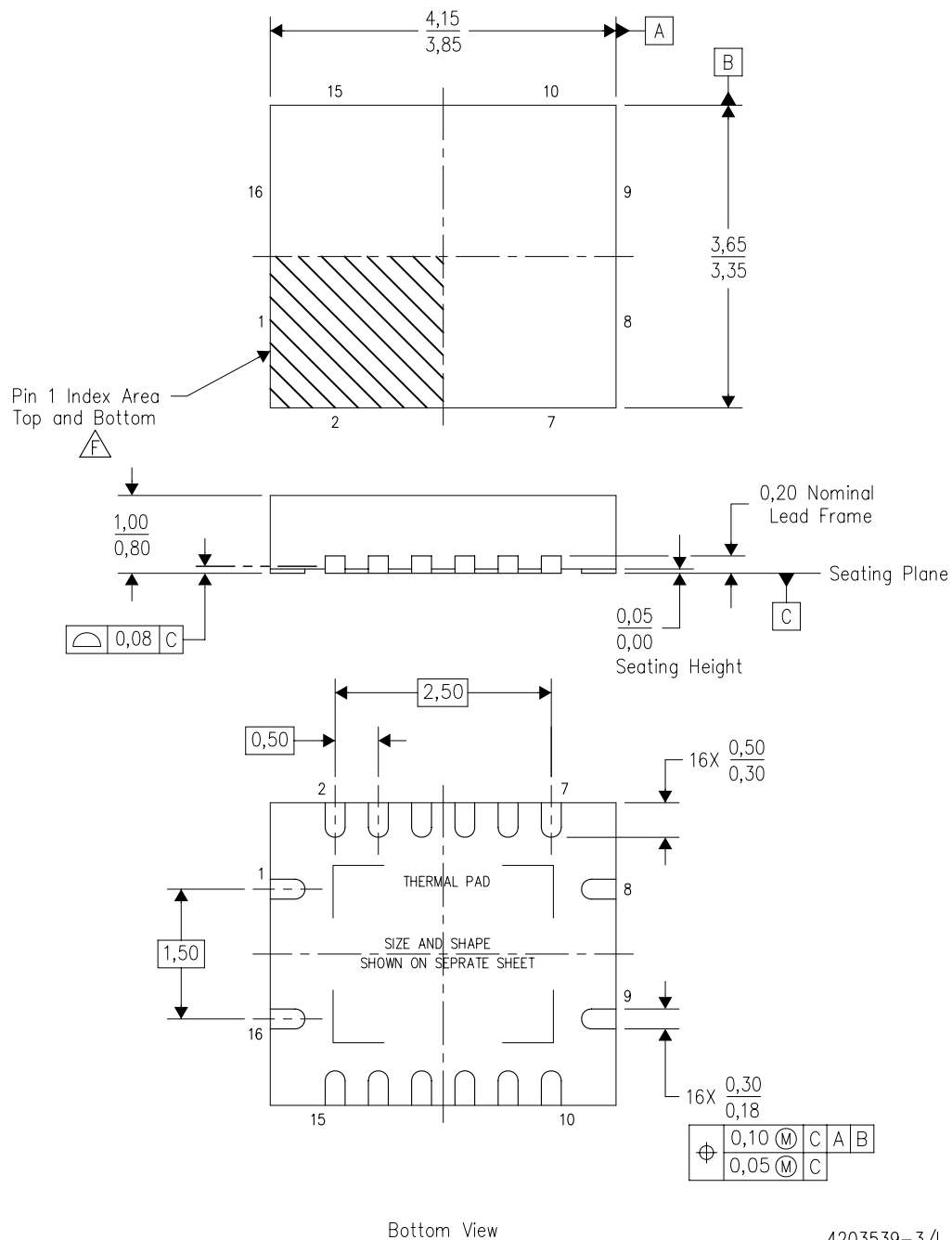
4214846/A 03/2014

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-3/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - This drawing is subject to change without notice.
  - QFN (Quad Flatpack No-Lead) package configuration.
  - The package thermal pad must be soldered to the board for thermal and mechanical performance.
  - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F** Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N16)

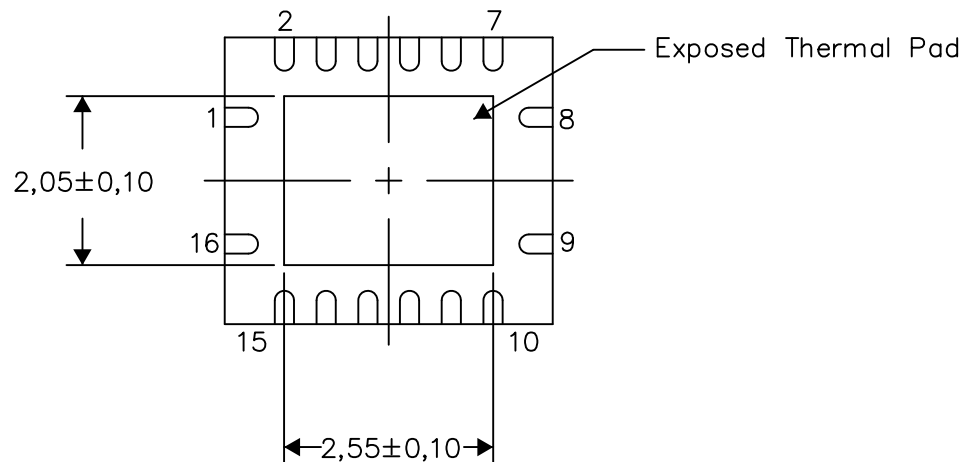
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



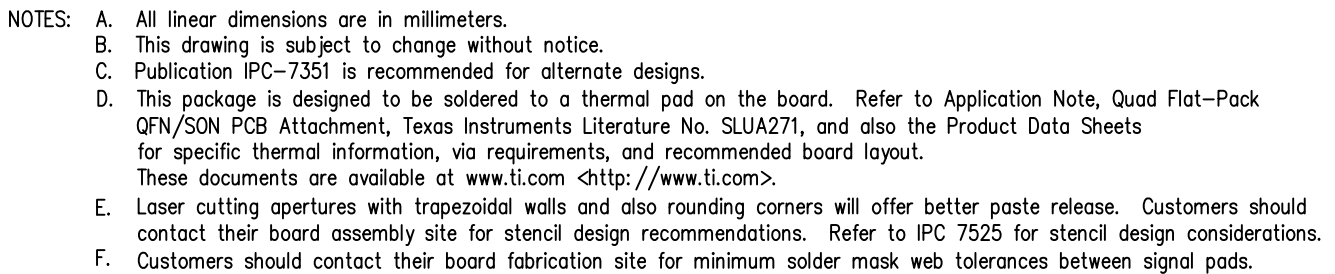
Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters





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